

## 1. General description

Planar passivated four quadrant triac in a SOT78 (TO-220AB) plastic package intended for use in applications requiring high bidirectional transient and blocking voltage capability and high thermal cycling performance. Typical applications include motor control, industrial and domestic lighting, heating and static switching.

## 2. Features and benefits

- High blocking voltage capability
- Less sensitive gate for improved noise immunity
- Planar passivated for voltage ruggedness and reliability
- Triggering in all four quadrants

## 3. Applications

- General purpose motor control
- General purpose switching

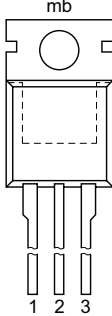
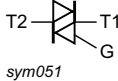
## 4. Quick reference data

Table 1. Quick reference data

| Symbol                         | Parameter                            | Conditions  | Values |     |     | Unit               |
|--------------------------------|--------------------------------------|---|--------|-----|-----|--------------------|
| <b>Absolute maximum rating</b> |                                      |   |        |     |     |                    |
| $V_{DRM}$                      | repetitive peak off-state voltage    |   | 600    |     |     | V                  |
| $I_{T(RMS)}$                   | RMS on-state current                 | full sine wave; $T_{mb} \leq 99\text{ }^{\circ}\text{C}$ ;<br><a href="#">Fig. 1</a> ; <a href="#">Fig. 2</a> ; <a href="#">Fig. 3</a>        | 12     |     |     | A                  |
| $I_{TSM}$                      | non-repetitive peak on-state current | full sine wave; $T_{j(\text{init})} = 25\text{ }^{\circ}\text{C}$ ;<br>$t_p = 20\text{ ms}$ ; <a href="#">Fig. 4</a> ; <a href="#">Fig. 5</a> | 95     |     |     | A                  |
| $T_j$                          | junction temperature                 |   | 125    |     |     | $^{\circ}\text{C}$ |
| Symbol                         | Parameter                            | Conditions  | Min    | Typ | Max | Unit               |
| <b>Static characteristics</b>  |                                      |   |        |     |     |                    |
| $I_{GT}$                       | gate trigger current                 | $V_D = 12\text{ V}$ ; $I_T = 0.1\text{ A}$ ; T2+ G+;<br>$T_j = 25\text{ }^{\circ}\text{C}$ ; <a href="#">Fig. 7</a>                           | -      | 5   | 35  | mA                 |
|                                |                                      | $V_D = 12\text{ V}$ ; $I_T = 0.1\text{ A}$ ; T2+ G-;<br>$T_j = 25\text{ }^{\circ}\text{C}$ ; <a href="#">Fig. 7</a>                           | -      | 8   | 35  | mA                 |
|                                |                                      | $V_D = 12\text{ V}$ ; $I_T = 0.1\text{ A}$ ; T2- G-;<br>$T_j = 25\text{ }^{\circ}\text{C}$ ; <a href="#">Fig. 7</a>                           | -      | 10  | 35  | mA                 |
|                                |                                      | $V_D = 12\text{ V}$ ; $I_T = 0.1\text{ A}$ ; T2- G+;<br>$T_j = 25\text{ }^{\circ}\text{C}$ ; <a href="#">Fig. 7</a>                           | -      | 22  | 70  | mA                 |
| <b>Dynamic characteristics</b> |                                      |   |        |     |     |                    |
| $dV_D/dt$                      | rate of rise of off-state voltage    | $V_{DM} = 402\text{ V}$ ; $T_j = 125\text{ }^{\circ}\text{C}$ ; ( $V_{DM} = 67\%$ of $V_{DRM}$ ); exponential waveform; gate open circuit     | 100    | 250 | -   | V/ $\mu\text{s}$   |

## 5. Pinning information

Table 2. Pinning information

| Pin | Symbol | Description                    | Simplified outline  | Graphic symbol  |
|-----|--------|--------------------------------|---|---|
| 1   | T1     | main terminal 1                |  | <br>sym051 |
| 2   | T2     | main terminal 2                |   |   |
| 3   | G      | gate                           |   |   |
| mb  | T2     | mounting base; main terminal 2 |   |   |

## 6. Ordering information

Table 3. Ordering information

| Type number | Package  |  |         |
|-------------|----------|--|---------|
|             | Name     | Description  | Version |
| BT138-600   | TO-220AB | plastic single-ended package; heatsink mounted; 1 mounting hole; 3-lead TO-220AB | SOT78   |

## 7. Marking

Table 4. Marking codes

| Type number | Marking codes |
|-------------|---------------|
| BT138-600   | BT138-600     |

## 8. Limiting values

**Table 5. Limiting values**

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol       | Parameter                            | Conditions  | Values     | Unit                   |
|--------------|--------------------------------------|---|------------|------------------------|
| $V_{DRM}$    | repetitive peak off-state voltage    |   | 600        | V                      |
| $I_{T(RMS)}$ | RMS on-state current                 | full sine wave; $T_{mb} \leq 99\text{ }^{\circ}\text{C}$ ;<br><a href="#">Fig 1</a> ; <a href="#">Fig 2</a> ; <a href="#">Fig 3</a>         | 12         | A                      |
| $I_{TSM}$    | non-repetitive peak on-state current | full sine wave; $T_{j(\text{init})} = 25\text{ }^{\circ}\text{C}$ ;<br>$t_p = 20\text{ ms}$ ; <a href="#">Fig 4</a> ; <a href="#">Fig 5</a> | 95         | A                      |
|              |                                      | full sine wave; $T_{j(\text{init})} = 25\text{ }^{\circ}\text{C}$ ;<br>$t_p = 16.7\text{ ms}$   | 105        | A                      |
| $I^2t$       | $I^2t$ for fusing                    | $t_p = 10\text{ ms}$ ; sine-wave pulse  | 45         | $\text{A}^2\text{s}$   |
| $di_T/dt$    | rate of rise of on-state current     | $I_G = 70\text{ mA}$ ; T2+ G+   | 50         | $\text{A}/\mu\text{s}$ |
|              |                                      | $I_G = 70\text{ mA}$ ; T2+ G-   | 50         | $\text{A}/\mu\text{s}$ |
|              |                                      | $I_G = 70\text{ mA}$ ; T2- G-   | 50         | $\text{A}/\mu\text{s}$ |
|              |                                      | $I_G = 140\text{ mA}$ ; T2- G+  | 10         | $\text{A}/\mu\text{s}$ |
| $I_{GM}$     | peak gate current                    |   | 2          | A                      |
| $P_{GM}$     | peak gate power                      |   | 5          | W                      |
| $P_{G(AV)}$  | average gate power                   | over any 20 ms period   | 0.5        | W                      |
| $T_{stg}$    | storage temperature                  |   | -40 to 150 | $^{\circ}\text{C}$     |
| $T_j$        | junction temperature                 |   | 125        | $^{\circ}\text{C}$     |

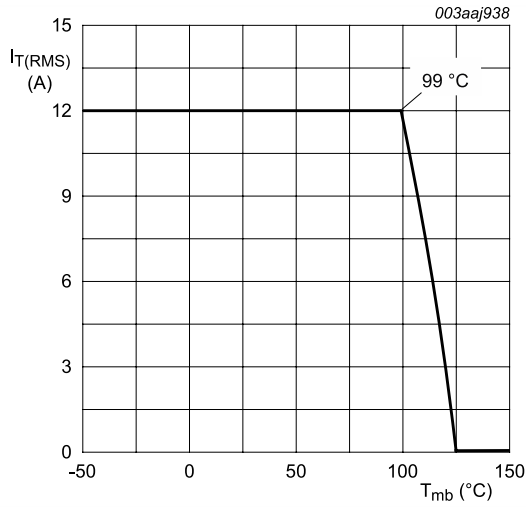
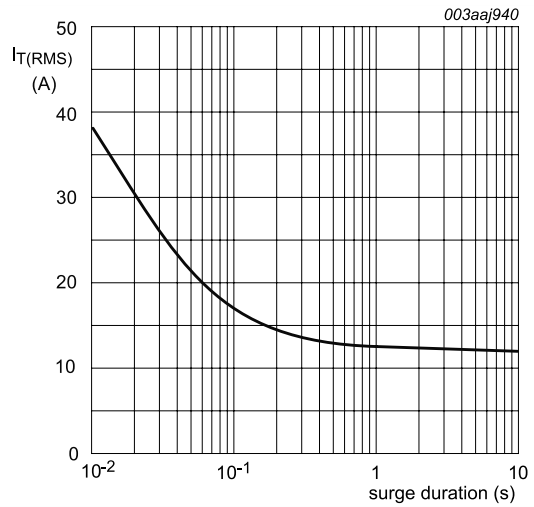


Fig. 1. RMS on-state current as a function of mounting base temperature; maximum values



f = 50 Hz; T<sub>mb</sub> = 99 °C

Fig. 2. RMS on-state current as a function of surge duration; maximum values

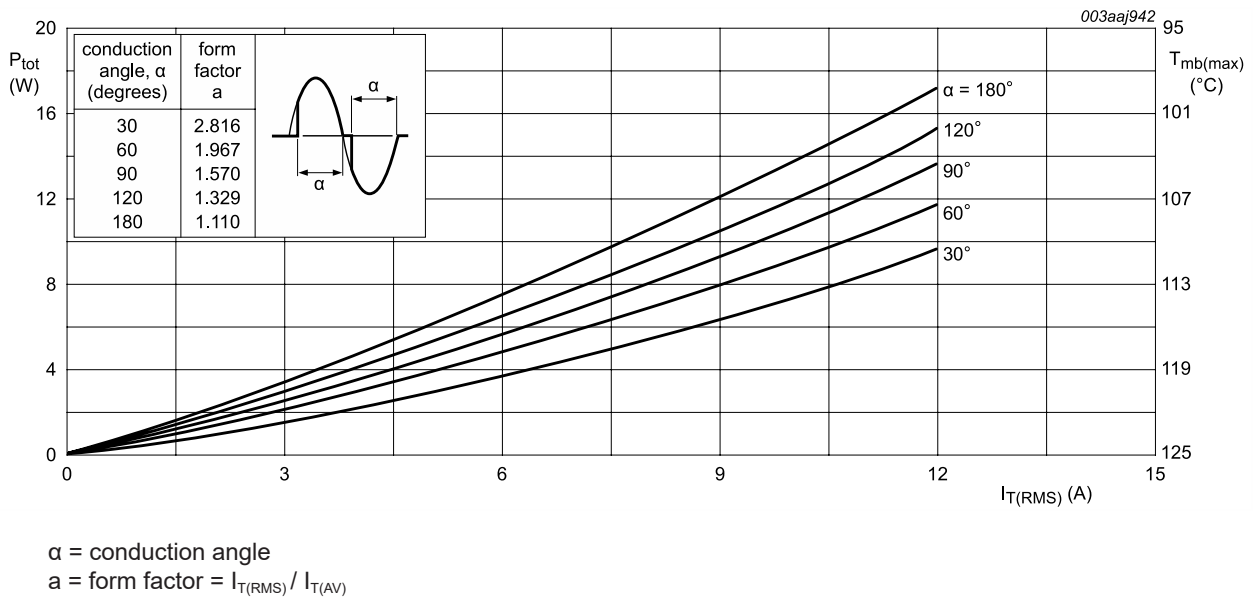


Fig. 3. Total power dissipation as a function of RMS on-state current; maximum values

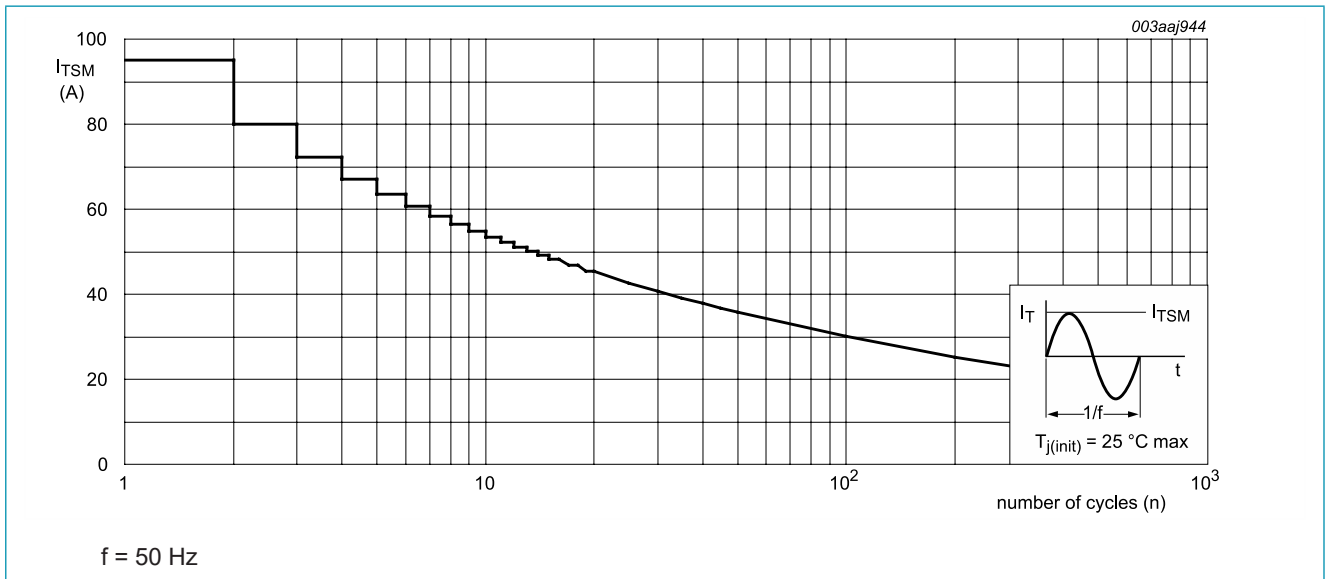


Fig. 4. Non-repetitive peak on-state current as a function of the number of sinusoidal current cycles; maximum values

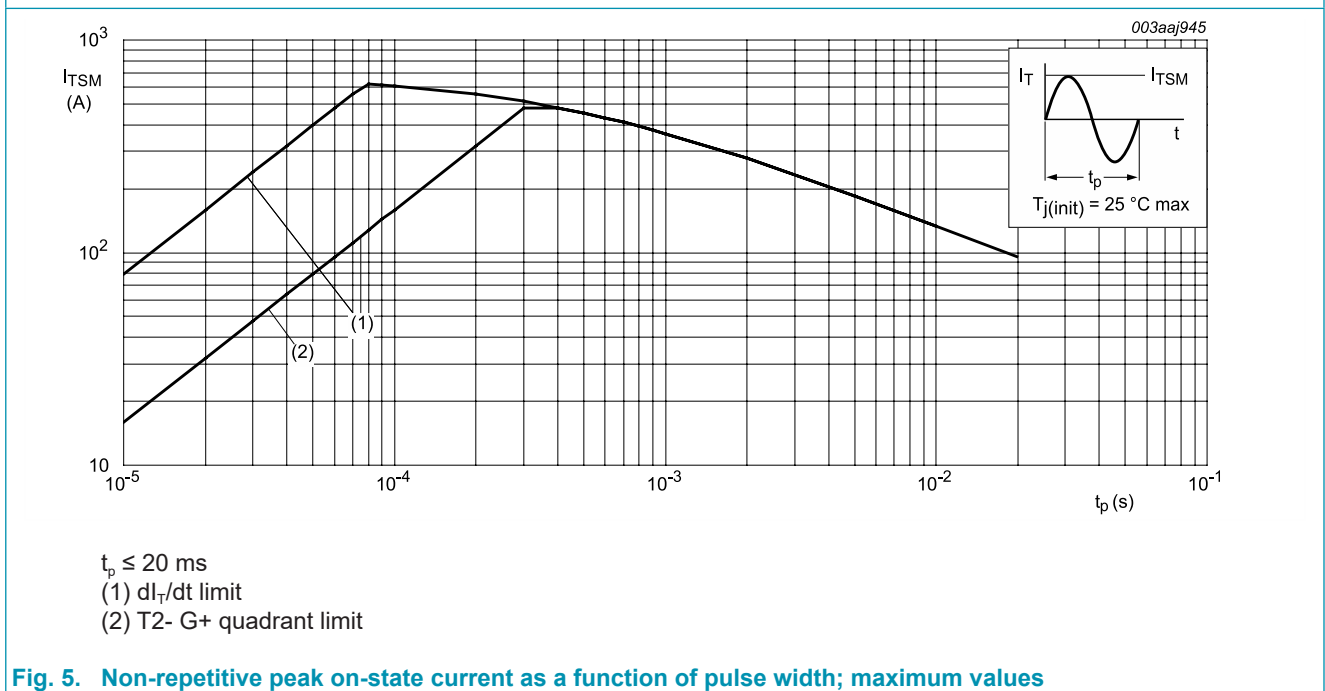


Fig. 5. Non-repetitive peak on-state current as a function of pulse width; maximum values

## 9. Thermal characteristics

Table 6. Thermal characteristics

| Symbol         | Parameter   | Conditions        | Min | Typ | Max | Unit |
|----------------|---|-------------------|-----|-----|-----|------|
| $R_{th(j-mb)}$ | thermal resistance from junction to mounting base | full cycle; Fig 6 | -   | -   | 1.5 | K/W  |
|                |   | half cycle; Fig 6 | -   | -   | 2   | K/W  |
| $R_{th(j-a)}$  | thermal resistance from junction to ambient       | in free air       | -   | 60  | -   | K/W  |

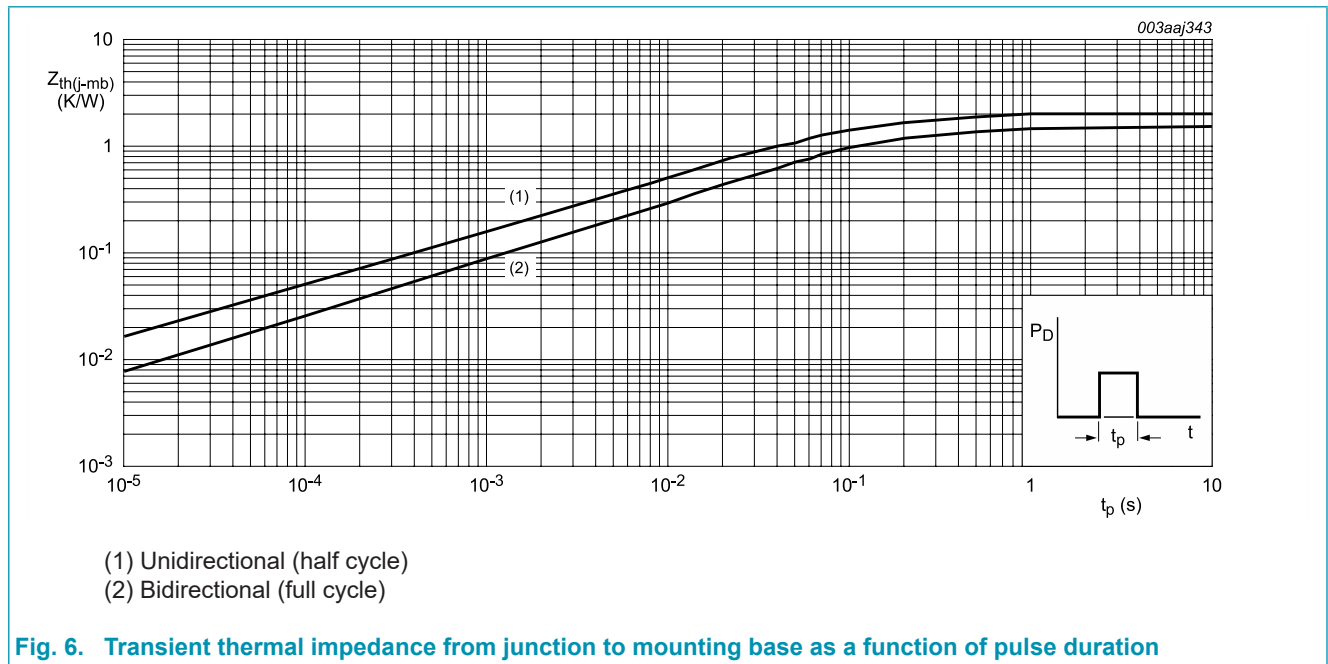
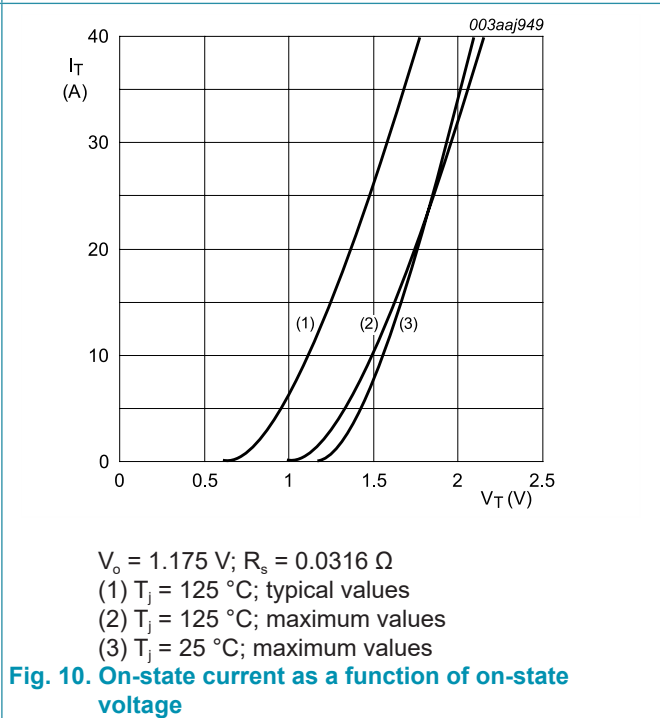
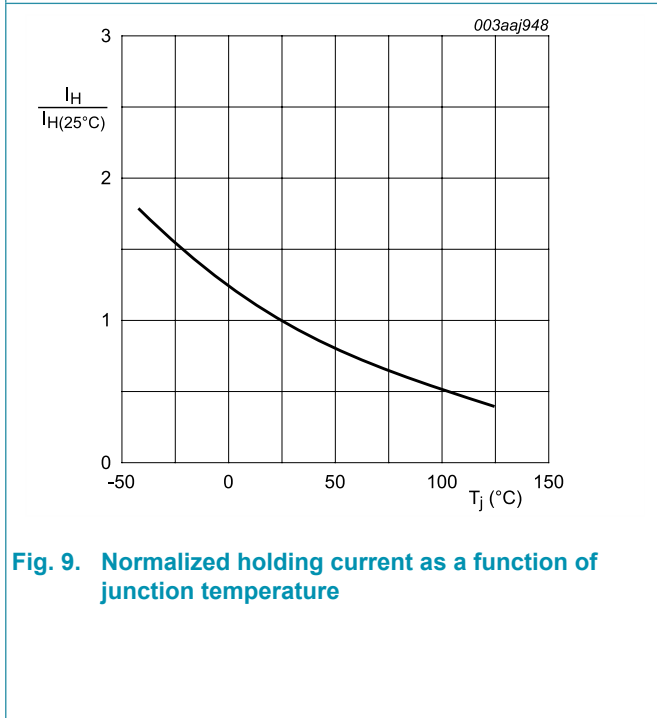
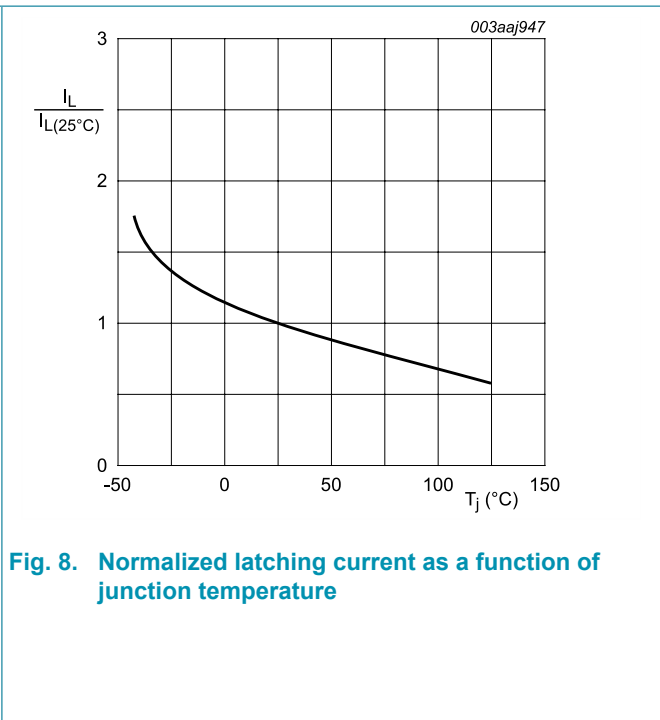
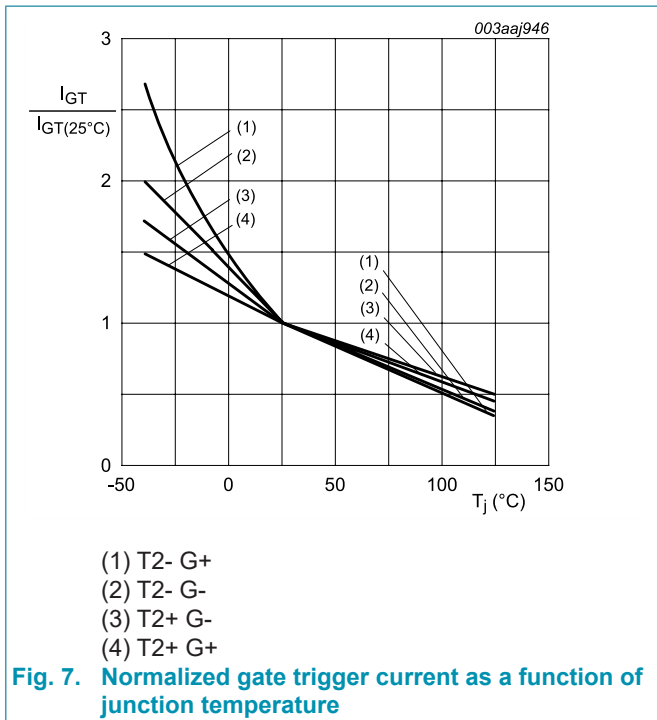


Fig. 6. Transient thermal impedance from junction to mounting base as a function of pulse duration

## 10. Characteristics

Table 7. Characteristics

| Symbol                         | Parameter                         | Conditions  | Min  | Typ | Max  | Unit       |
|--------------------------------|-----------------------------------|---|------|-----|------|------------|
| <b>Static characteristics</b>  |                                   |   |      |     |      |            |
| $I_{GT}$                       | gate trigger current              | $V_D = 12\text{ V}$ ; $I_T = 0.1\text{ A}$ ; T2+ G+;<br>$T_j = 25\text{ °C}$ ; <a href="#">Fig. 7</a>                       | -    | 5   | 35   | mA         |
|                                |                                   | $V_D = 12\text{ V}$ ; $I_T = 0.1\text{ A}$ ; T2+ G-;<br>$T_j = 25\text{ °C}$ ; <a href="#">Fig. 7</a>                       | -    | 8   | 35   | mA         |
|                                |                                   | $V_D = 12\text{ V}$ ; $I_T = 0.1\text{ A}$ ; T2- G-;<br>$T_j = 25\text{ °C}$ ; <a href="#">Fig. 7</a>                       | -    | 10  | 35   | mA         |
|                                |                                   | $V_D = 12\text{ V}$ ; $I_T = 0.1\text{ A}$ ; T2- G+;<br>$T_j = 25\text{ °C}$ ; <a href="#">Fig. 7</a>                       | -    | 22  | 70   | mA         |
| $I_L$                          | latching current                  | $V_D = 12\text{ V}$ ; $I_G = 0.1\text{ A}$ ; T2+ G+;<br>$T_j = 25\text{ °C}$ ; <a href="#">Fig. 8</a>                       | -    | 7   | 40   | mA         |
|                                |                                   | $V_D = 12\text{ V}$ ; $I_G = 0.1\text{ A}$ ; T2+ G-;<br>$T_j = 25\text{ °C}$ ; <a href="#">Fig. 8</a>                       | -    | 20  | 60   | mA         |
|                                |                                   | $V_D = 12\text{ V}$ ; $I_G = 0.1\text{ A}$ ; T2- G-;<br>$T_j = 25\text{ °C}$ ; <a href="#">Fig. 8</a>                       | -    | 8   | 40   | mA         |
|                                |                                   | $V_D = 12\text{ V}$ ; $I_G = 0.1\text{ A}$ ; T2- G+;<br>$T_j = 25\text{ °C}$ ; <a href="#">Fig. 8</a>                       | -    | 10  | 60   | mA         |
| $I_H$                          | holding current                   | $V_D = 12\text{ V}$ ; $T_j = 25\text{ °C}$ ; <a href="#">Fig. 9</a>   | -    | 6   | 30   | mA         |
| $V_T$                          | on-state voltage                  | $I_T = 15\text{ A}$ ; $T_j = 25\text{ °C}$ ; <a href="#">Fig. 10</a>  | -    | 1.4 | 1.65 | V          |
| $V_{GT}$                       | gate trigger voltage              | $V_D = 12\text{ V}$ ; $I_T = 0.1\text{ A}$ ; $T_j = 25\text{ °C}$ ;<br><a href="#">Fig. 11</a>                              | -    | 0.7 | 1    | V          |
|                                |                                   | $V_D = 400\text{ V}$ ; $I_T = 0.1\text{ A}$ ; $T_j = 125\text{ °C}$ ;<br><a href="#">Fig. 11</a>                            | 0.25 | 0.4 | -    | V          |
| $I_D$                          | off-state current                 | $V_D = 600\text{ V}$ ; $T_j = 125\text{ °C}$  | -    | 0.1 | 0.5  | mA         |
| <b>Dynamic characteristics</b> |                                   |   |      |     |      |            |
| $dV_D/dt$                      | rate of rise of off-state voltage | $V_{DM} = 402\text{ V}$ ; $T_j = 125\text{ °C}$ ; ( $V_{DM} = 67\%$ of $V_{DRM}$ ); exponential waveform; gate open circuit | 100  | 250 | -    | V/ $\mu$ s |
| $t_{gt}$                       | gate-controlled turn-on time      | $I_{TM} = 16\text{ A}$ ; $V_D = 600\text{ V}$ ; $I_G = 0.1\text{ A}$ ; $dI_G/dt = 5\text{ A}/\mu\text{s}$                   | -    | 2   | -    | $\mu$ s    |





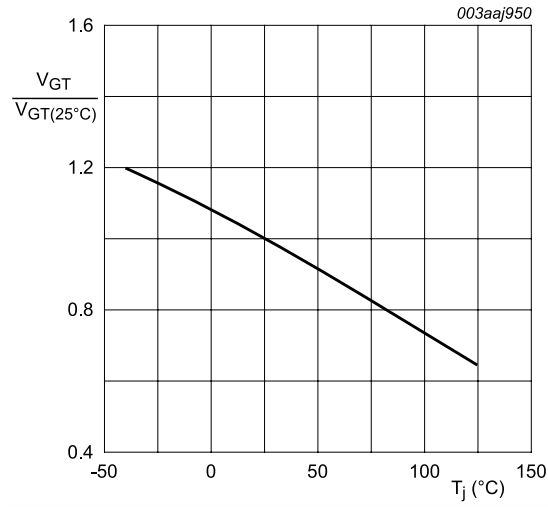


Fig. 11. Normalized gate trigger voltage as a function of junction temperature

### 11. Package outline

Plastic single-ended package; heatsink mounted; 1 mounting hole; 3-lead TO-220AB

SOT78



**DIMENSIONS (mm are the original dimensions)**

| UNIT | A          | A <sub>1</sub> | b          | b <sub>1</sub> (2) | b <sub>2</sub> (2) | c          | D            | D <sub>1</sub> | E           | e    | L            | L <sub>1</sub> (1) | L <sub>2</sub> (1)<br>max. | p          | q          | Q          |
|------|------------|----------------|------------|--------------------|--------------------|------------|--------------|----------------|-------------|------|--------------|--------------------|----------------------------|------------|------------|------------|
| mm   | 4.7<br>4.1 | 1.40<br>1.25   | 0.9<br>0.6 | 1.6<br>1.0         | 1.3<br>1.0         | 0.7<br>0.4 | 16.0<br>15.2 | 6.6<br>5.9     | 10.3<br>9.7 | 2.54 | 15.0<br>12.8 | 3.30<br>2.79       | 3.0                        | 3.8<br>3.5 | 3.0<br>2.7 | 2.6<br>2.2 |

**Notes**

1. Lead shoulder designs may vary.
2. Dimension includes excess dambar.

| OUTLINE VERSION | REFERENCES |                 |       |  | EUROPEAN PROJECTION | ISSUE DATE           |
|-----------------|------------|-----------------|-------|--|---------------------|----------------------|
|                 | IEC        | JEDEC           | JEITA |  |                     |                      |
| SOT78           |            | 3-lead TO-220AB | SC-46 |  |                     | 08-04-23<br>08-06-13 |

## 12. Legal information

### Data sheet status

| Document status [1][2]         | Product status [3] | Definition  |
|--------------------------------|--------------------|---|
| Objective [short] data sheet   | Development        | This document contains data from the objective specification for product development. |
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- [1] Please consult the most recently issued document before initiating or completing a design.
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Date of release: 16 March 2018

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